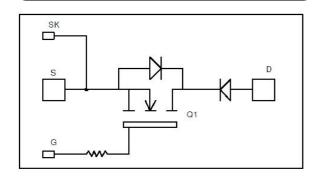


Single switch with Series diode MOSFET Power Module

$$\begin{split} V_{DSS} &= 1000V \\ R_{DSon} &= 65 m \Omega \ typ \ @ \ Tj = 25^{\circ}C \\ I_D &= 145 A \ @ \ Tc = 25^{\circ}C \end{split}$$



Application

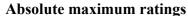
Zero Current Switching resonant mode

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration
- AlN substrate for improved thermal performance



- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant



Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		1000	V
Ţ	Continuous Drain Current	$T_c = 25$ °C	145	
I_D	Continuous Drain Current	$T_c = 80$ °C	110	A
I_{DM}	Pulsed Drain current		580	
V_{GS}	Gate - Source Voltage		±30	V
R _{DSon}	Drain - Source ON Resistance		78	$m\Omega$
P_{D}	Maximum Power Dissipation $T_c = 25^{\circ}C$		3250	W
I_{AR}	Avalanche current (repetitive and non repetitive)		30	A
E _{AR}	Repetitive Avalanche Energy		50	I
E_{AS}	Single Pulse Avalanche Energy		3200	mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



All ratings @ $T_j = 25$ °C unless otherwise specified

Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
I_{DSS}	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1000V$	$T_j = 25^{\circ}C$			400	μΑ
		$V_{GS} = 0V, V_{DS} = 800V$	$T_j = 125$ °C			2	mA
R _{DS(on)}	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 72.5A$			65	78	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 20 \text{mA}$		3		5	V
I_{GSS}	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$				±400	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C_{iss}	Input Capacitance	$V_{GS} = 0V$		28.5		
C_{oss}	Output Capacitance	$V_{DS} = 25V$		5.08		nF
C_{rss}	Reverse Transfer Capacitance	f = 1MHz		0.9		
Q_{g}	Total gate Charge	$V_{GS} = 10V$		1068		
$Q_{\rm gs}$	Gate – Source Charge	$V_{\text{Bus}} = 500V$		136		nC
Q_{gd}	Gate – Drain Charge	$I_D = 145A$		692		
$T_{d(on)}$	Turn-on Delay Time	$V_{GS} = 15V$		18		
T_{r}	Rise Time	$V_{\text{Bus}} = 500 \text{V}$		14		na
$T_{d(off)}$	Turn-off Delay Time	$I_{D} = 145A$		140		ns
T_{f}	Fall Time	$R_G = 0.75\Omega$		55		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		4.8		m I
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 145A, R_G = 0.75\Omega$		2.9		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		8	·	m I
E_{off}	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 145A, R_G = 0.75\Omega$		3.9		mJ

Series diode ratings and characteristics

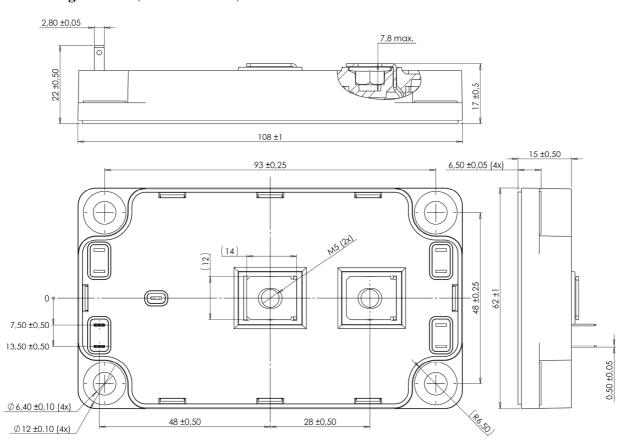
Symbol	Characteristic Test Conditions			Min	Typ	Max	Unit
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1000			V
I_{RM}	Maximum Reverse Leakage Current	$V_{p}=1000V$	$T_j = 25$ °C			750	μA
1KM			$T_j = 125$ °C			1000	μπ
I_F	DC Forward Current		$Tc = 80^{\circ}C$		240		A
	Diode Forward Voltage	$I_F = 240A$			2	2.5	
$V_{\rm F}$		$I_F = 480A$			2.2		V
		$I_F = 240A$	$T_j = 125$ °C		1.7		
+	Reverse Recovery Time	$I_F = 240A$ $V_R = 667V$	$T_j = 25$ °C		280		ns
t_{rr}			$T_j = 125$ °C		350		115
Q _{rr}	Reverse Recovery Charge	$di/dt = 800A/\mu s$	$T_j = 25$ °C		3.04		μC
			$T_{j} = 125^{\circ}C$		14.4		μС



Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance		Transistor			0.038	°C/W
IX _{th} JC			Series diode			0.23	C/ VV
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
$T_{\rm J}$	Operating junction temperature range			-40		150	
T_{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M6	3		5	N.m
		For teminals	M5	2		3.5	18.111
Wt	Package Weight	·				300	g

SP6 Package outline (dimensions in mm)

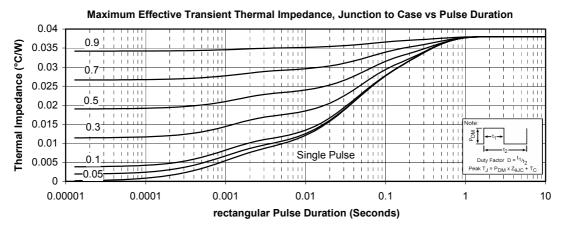


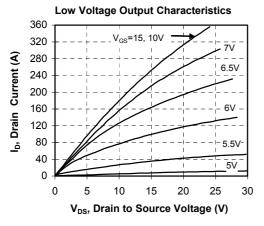
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

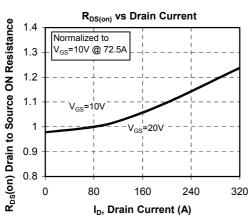
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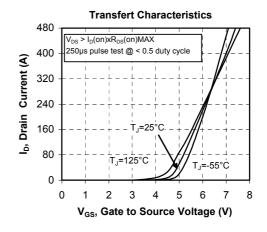


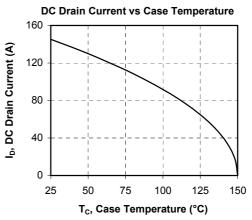
Typical Performance Curve





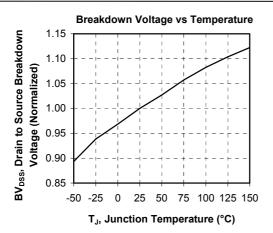


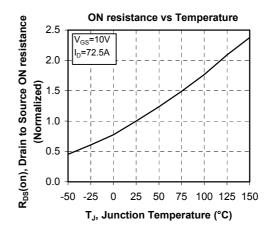


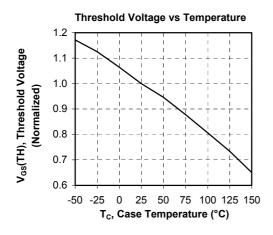


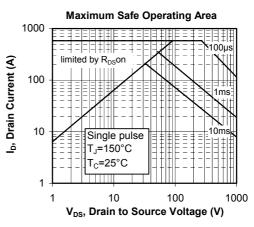
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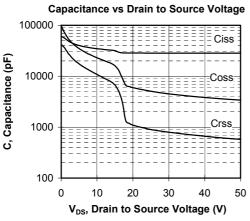


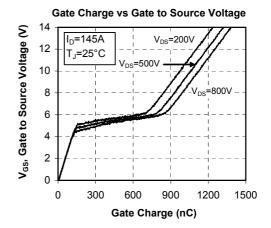




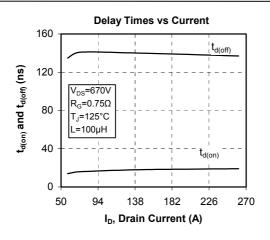


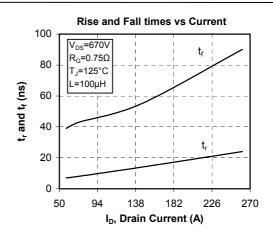


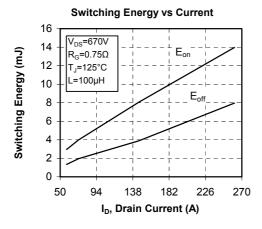


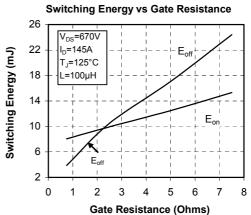


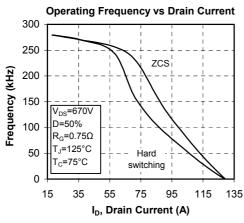


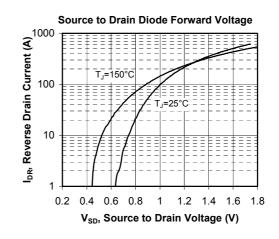












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7 - 7

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